

**Features**

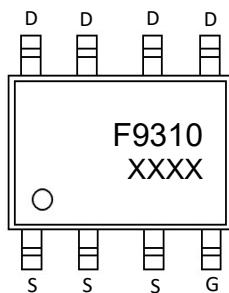
- Lower Conduction Losses
- Multi-Vendor Compatibility
- 100% avalanche tested
- Environmentally Friendlier

**Application**

- Switch Mode Power Supply (SMPS)
- Motor Controls

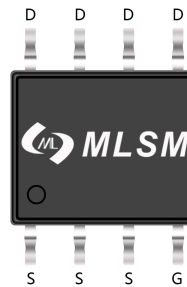
**Product Summary**

$V_{DS}$	$R_{DS(ON)}$ MAX	$I_D$ MAX
-30	4.6mΩ@-10V	-20
	6.8mΩ@-4.5V	

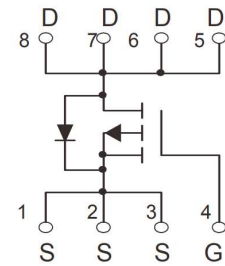


F9310 : Device code  
 XXXX : Code

Marking and pin assignment



SOP-8 top view



Schematic diagram



Halogen-Free

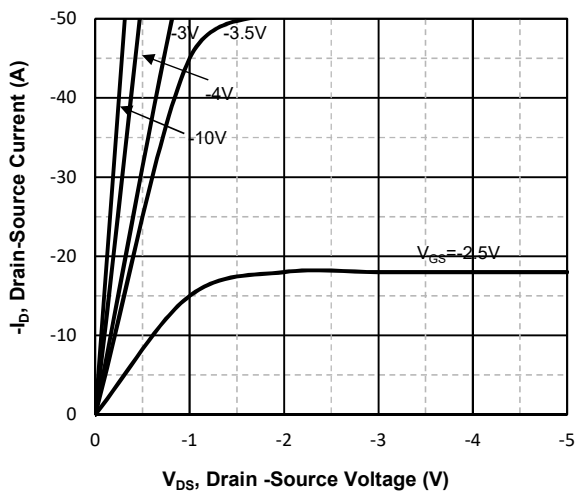
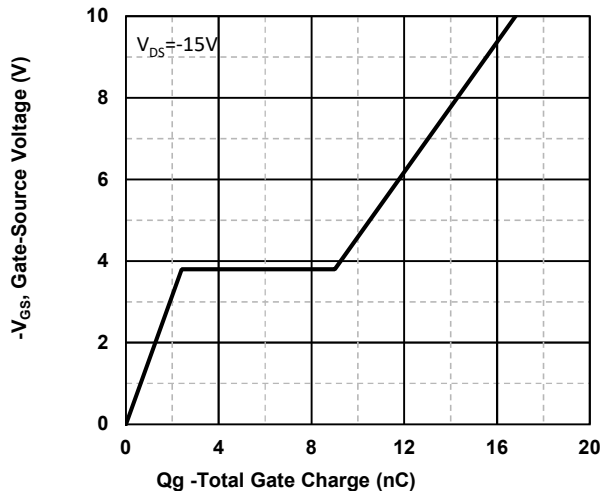
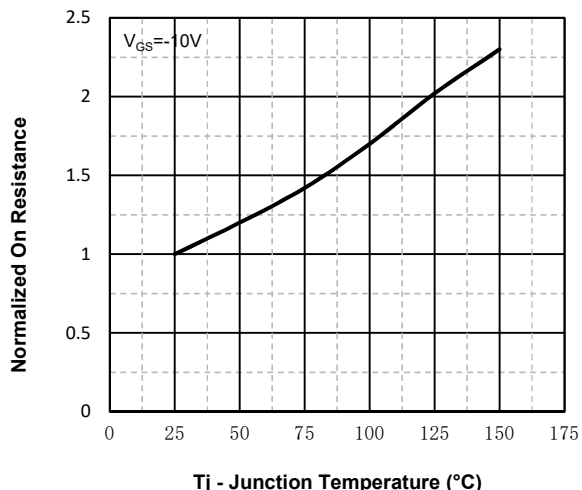
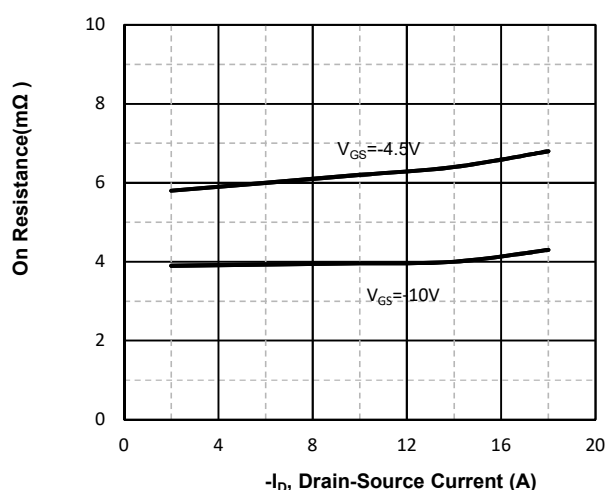
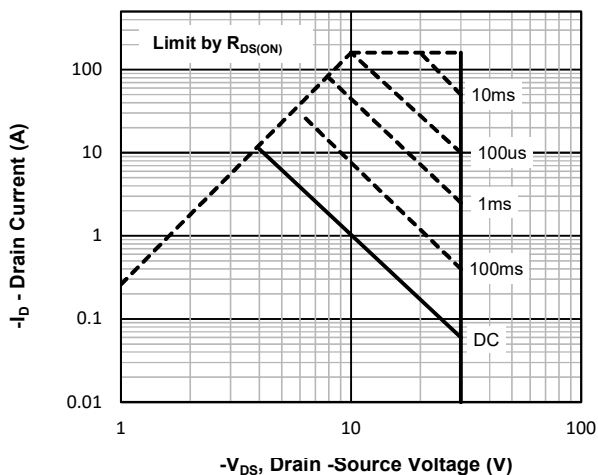
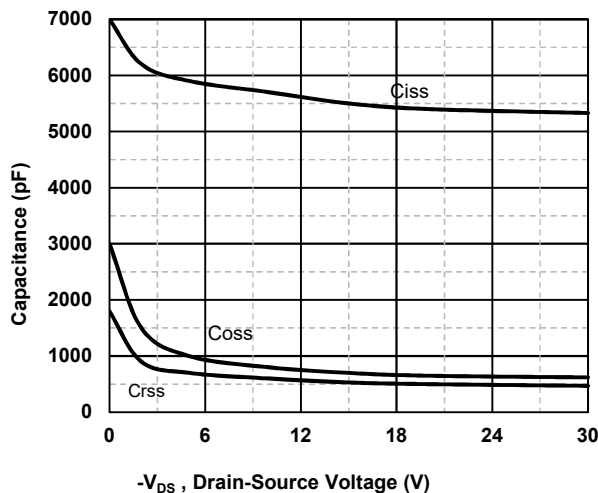
**Absolute Maximum Ratings (TA=25°C unless otherwise noted)**

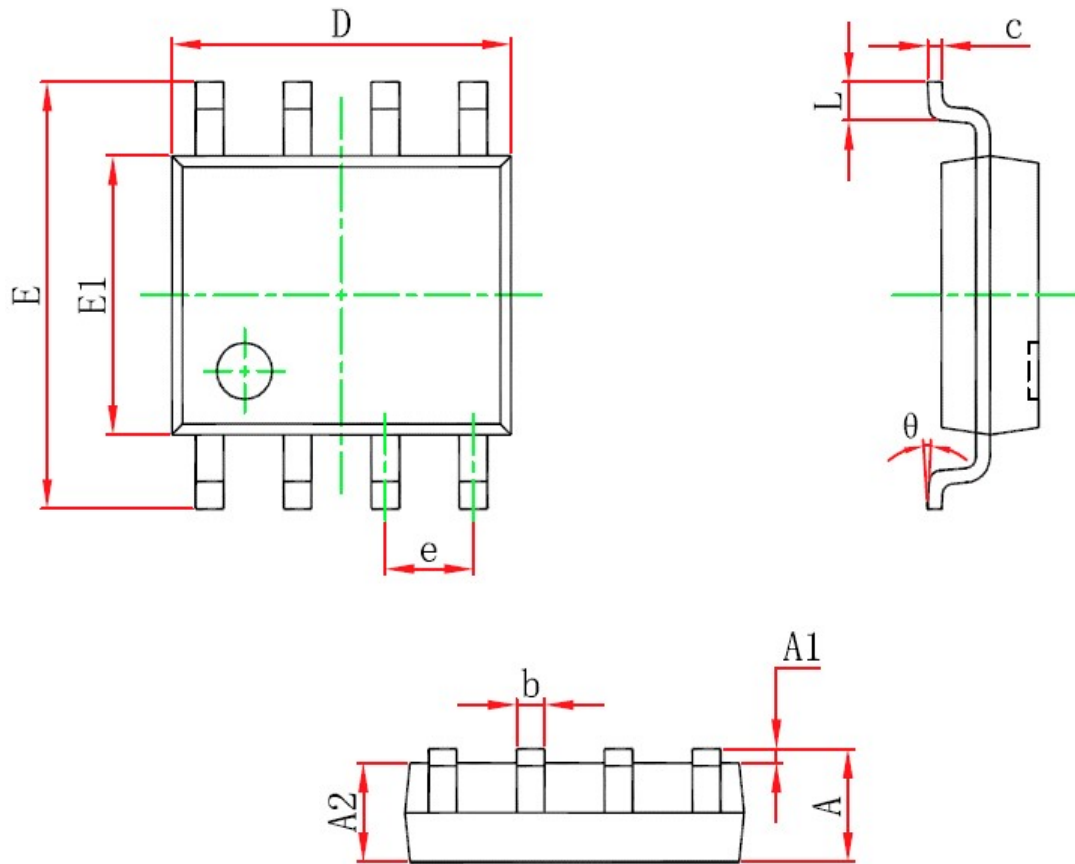
Symbol	Parameter	Rating	Unit
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>			
$V_{DS}$	Drain-Source Breakdown Voltage	-30	V
$V_{GS}$	Gate-Source Voltage	±20	V
$T_J$	Maximum Junction Temperature	150	°C
$T_{STG}$	Storage Temperature Range	-50 to 155	°C
$I_S$	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$ -20	A
<b>Mounted on Large Heat Sink</b>			
$I_{DM}$	Pulse Drain Current Tested	$T_c=25^\circ\text{C}$ -160	A
$I_D$	Continuous Drain Current	$T_c=25^\circ\text{C}$ -20	A
$P_D$	Maximum Power Dissipation	$T_c=25^\circ\text{C}$ 2.5	W
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient	83	°C/W

**Ordering Information (Example)**

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
IRF9310	SOP-8	F9310	3,000	6,000	42,000	13"reel

Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	-30	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	--	--	-1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.3	-1.8	-2.4	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	--	3.9	4.6	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-16A	--	5.8	6.8	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1MHz	--	5500	--	pF
C <sub>OSS</sub>	Output Capacitance		--	720	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	500	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =-10V, I <sub>D</sub> =-20A, V <sub>GS</sub> =-15V	--	30	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	5.5	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	7.5	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =-15V, I <sub>D</sub> =-20A, V <sub>GS</sub> =-10V, R <sub>G</sub> =25Ω	--	13	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	20	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	90	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	65	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =-20A	--	--	1.2	V

**Typical Operating Characteristics**

**Fig1. Typical Output Characteristics**

**Fig2. Typical Gate Charge Vs. Gate-Source Voltage**

**Fig3. Normalized On-Resistance Vs. Temperature**

**Fig4. On-Resistance Vs. Drain-Source Current**

**Fig5. Maximum Safe Operating Area**

**Fig6 Typical Capacitance Vs. Drain-Source Voltage**

**SOP-8 Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions in Inches	
	Min	Max	Min	Max
A	1.450	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
e	1.270(BSC)		0.050(BSC)	
E	5.800	6.200	0.028	0.035
E1	3.800	4.000	0.057	0.069
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°